



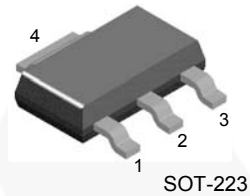
February 2015



# FZT790A PNP Low Saturation Transistor

## Description

These devices are designed with high current gain and low saturation voltage with collector currents up to 3 A continuous.



1. Base 2.4. Collector 3. Emitter

## Ordering Information

Part Number	Marking	Package	Packing Method
FZT790A	790A	SOT-223 4L	Tape and Reel

## Absolute Maximum Ratings<sup>(1),(2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$V_{CEO}$	Collector-Emitter Voltage	-40	V
$V_{CBO}$	Collector-Base Voltage	-50	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current - Continuous	-3	A
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

### Notes:

1. These ratings are based on a maximum junction temperature of  $150^\circ\text{C}$ .
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

**Thermal Characteristics<sup>(3)</sup>**

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Max.	Unit
$P_D$	Total Power Dissipation	2	W
	Derate Above $25^\circ\text{C}$	16	mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	62.5	$^\circ\text{C}/\text{W}$

**Note:**

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

**Electrical Characteristics**

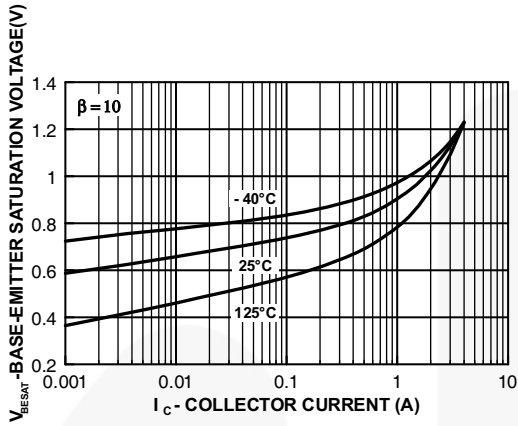
Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -10\text{ mA}, I_B = 0$	-40		V
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C = -100\ \mu\text{A}, I_E = 0$	-50		V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = -100\ \mu\text{A}, I_C = 0$	-5.0		V
$I_{CBO}$	Collector Cut-Off Current	$V_{CB} = -30\text{ V}, I_E = 0$		-100	nA
		$V_{CB} = -30\text{ V}, I_E = 0, T_A = 100^\circ\text{C}$		-10	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-Off Current	$V_{EB} = -4\text{ V}, I_C = 0$		-100	nA
$h_{FE}$	DC Current Gain <sup>(4)</sup>	$V_{CE} = -2.0\text{ V}, I_C = -10\text{ mA}$	300	800	
		$V_{CE} = -2.0\text{ V}, I_C = -500\text{ mA}$	250		
		$V_{CE} = -2.0\text{ V}, I_C = -1.0\text{ A}$	200		
		$V_{CE} = -2.0\text{ V}, I_C = -2.0\text{ A}$	150		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage <sup>(4)</sup>	$I_C = -500\text{ mA}, I_B = -5.0\text{ mA}$		-0.25	V
		$I_C = -1.0\text{ A}, I_B = -10\text{ mA}$		-0.45	
		$I_C = -2.0\text{ A}, I_B = -20\text{ mA}$		-0.75	
$V_{BE(sat)}$	Base-Emitter Saturation Voltage <sup>(4)</sup>	$I_C = -1.0\text{ A}, I_B = -10\text{ mA}$		-1.0	V
$V_{BE(on)}$	Base-Emitter On Voltage <sup>(4)</sup>	$I_C = -1.0\text{ A}, V_{CE} = -2.0\text{ V}$		-1.0	V
$f_T$	Transition Frequency	$I_C = -50\text{ mA}, V_{CE} = -5.0\text{ V}, f = 50\text{ MHz}$	100		MHz

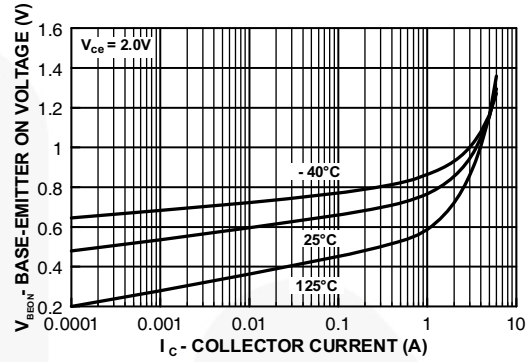
**Note:**

4. Pulse test: pulse width  $\leq 300\ \mu\text{s}$ , duty cycle  $\leq 2.0\%$

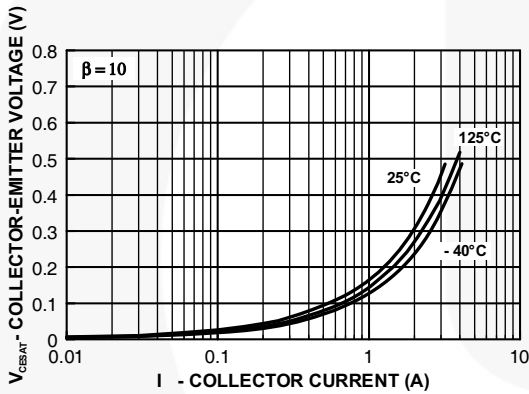
## Typical Performance Characteristics



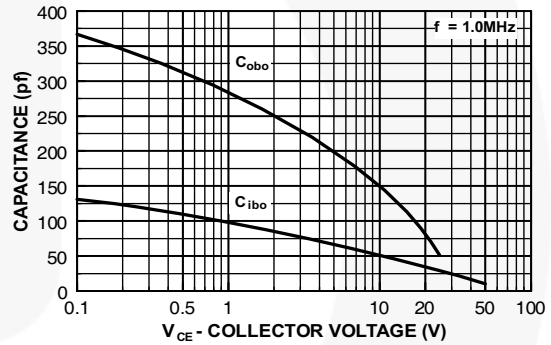
**Figure 1. Base-Emitter Saturation Voltage vs. Collector Current**



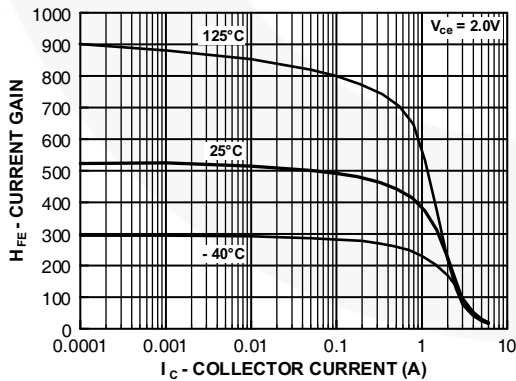
**Figure 2. Base-Emitter On Voltage vs. Collector Current**



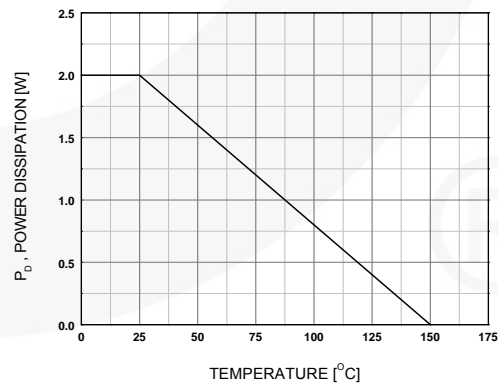
**Figure 3. Collector-Emitter Saturation Voltage vs. Collector Current**



**Figure 4. Input/Output Capacitance vs. Reverse Bias Voltage**



**Figure 5. Current Gain vs. Collector Current**



**Figure 6. Power Dissipation vs. Ambient Temperature**

Physical Dimensions

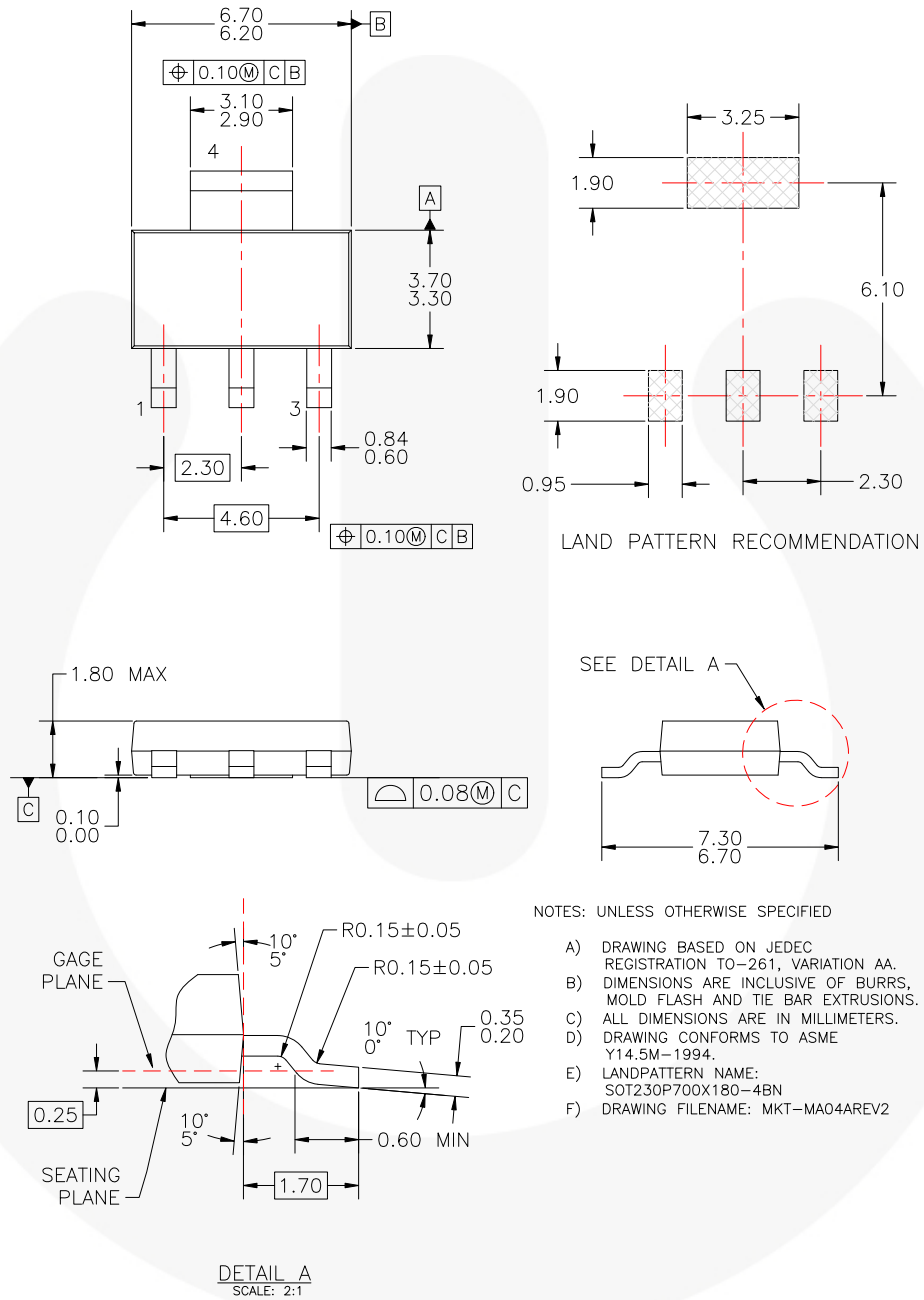







Figure 7. MOLDED PACKAGE, SOT-223, 4-LEAD



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